

## **Quarterly Reliability Monitoring Results**

## Quarters: Q1/2021 to Q4/2021

Based on structural similarity

| Supplier Nexperia B.V. Name of Laboratory |                             | User Part Number BC817-40QA Part Description            |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
|---|-----------------------------|---|-------------|-----------|------------|-----------|--|--|---------------------------|--|---------------|----------------|------------------|----|--|
|   |                             |   |             |           |            |           |  |  |                           |  | Nexperia DHAM | Small Signal E | Bipolar Transist | or |  |
|   |                             |   |             |           |            |           |  |  | Assembly reliability labs |  | MCD package   |                |                  |    |  |
| Based on AEC-Q101 Test                    |                             | Test Conditions   | Duration    | # Lots    | # Quantity | # Rejects |  |  |                           |  |               |                |                  |    |  |
|   | TEST                        |   |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
|   | Pre- and Post-Stress        |   |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
| # E1                                      | Electrical Test             | Tamb = 25 °C  | N/A         | see below | all parts  | see below |  |  |                           |  |               |                |                  |    |  |
|   |                             | JESD22-A113   |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
|   |                             | Bake Tamb = 125 °C                                      | 24 hours    |           |            |           |  |  |                           |  |               |                |                  |    |  |
|   | PC                          | Soak Tamb = 85 °C, RH = 85%                             | 168 hours   |           |            |           |  |  |                           |  |               |                |                  |    |  |
| # A1                                      | Preconditioning             | Reflow soldering  | 3 cycles    | 208       | 16640      | 0         |  |  |                           |  |               |                |                  |    |  |
|   |                             | MIL-STD-750-1   |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
|   | HTRB                        | M1039 Method A  |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
|   |                             | Tj = Tjmax, Vr = 100% of max. datasheet reverse voltage |             |           |            | _         |  |  |                           |  |               |                |                  |    |  |
| # B1                                      | Bias                        | reverse voitage   | 1000 hours  | 202       | 16160      | 0         |  |  |                           |  |               |                |                  |    |  |
|   | тс                          | JESD22-A104   |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
| <b>4</b> A 4                              | Temperature Cycling         | -65 °C to Timax, not to exceed 150°C                    | 1000 eveles | 52        | 4160       | 0         |  |  |                           |  |               |                |                  |    |  |
| # A4                                      | remperature cycling         | • '   | 1000 cycles | 52        | 4160       | U         |  |  |                           |  |               |                |                  |    |  |
|   | AC                          | JESD22-A102<br>Tamb = 121 °C, RH = 100 %                |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
| # A3 alt                                  | Autoclave                   | Pressure = 205 kPa (29.7 psia)                          | 96 hours    | 52        | 4160       | 0         |  |  |                           |  |               |                |                  |    |  |
| # A3 ait                                  | Addociave                   | 11c33d1c = 203 kt d (23.7 p3id)                         | 90 110015   | 32        | 4100       | U         |  |  |                           |  |               |                |                  |    |  |
|   | H3TRB                       | JESD22-A101   |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
|   | High Humidity High          | Tamb = 85 °C, RH = 85%, VR = 80 % of                    |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
| # A2 alt                                  | Temperature Reverse Bias    |   | 1000 hours  | 52        | 4160       | 0         |  |  |                           |  |               |                |                  |    |  |
| " 712 aic                                 |                             | MIL-STD-750 Method 1037                                 | 1000 110013 | JE        | 1100       | -         |  |  |                           |  |               |                |                  |    |  |
|   | IOL                         | ton = toff, devices powered to insure $\Delta T_i$ =    |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
| # A5                                      | Intermittent Operating Life |   | 1000 hours  | 52        | 4160       | 0         |  |  |                           |  |               |                |                  |    |  |
| " 713                                     | are to personny and         | ,   | 1000 110013 | 52        | 1100       | •         |  |  |                           |  |               |                |                  |    |  |
|   | RSH                         | JESD22-A111   |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
| # C8                                      | Resistance to Solder Heat   | 260 °C ± 5 °C   | 10 s        | n.a.      | n.a.       | n.a.      |  |  |                           |  |               |                |                  |    |  |
| 50  | SD                          |   |             |           |            |           |  |  |                           |  |               |                |                  |    |  |
| # C10                                     | Solderability               | J-STD-002   |             | 111       | 1110       | 0         |  |  |                           |  |               |                |                  |    |  |

<sup>[1]</sup> The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

## **Calculation of FIT and MTTF**

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1)
Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

| Wafer Fab | Technology           | Quantity | Rejects | Failure Rate (FIT) | MTTF (hrs) |
|-----------|----------------------|----------|---------|--------------------|------------|
| Nexperia  | Small Signal Bipolar |          |         |                    |            |
| DHAM      | Transistor           | 16160    | 0       | 0.26               | 3.81E+09   |

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